September 2001
Revised February 2005

74ALVC00
Low Voltage Quad 2-Input NAND Gate with 3.6V Tolerant Inputs and Outputs

General Description

The ALVC00 contains four 2-input NAND gates. This product is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The ALVC00 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

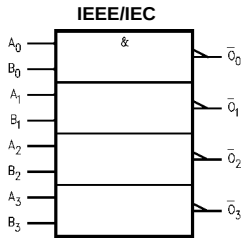
- 1.65V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
  - 3 ns max for 3.0V to 3.6V V_{CC}
  - 3.5 ns max for 2.3V to 2.7V V_{CC}
  - 4.4 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Uses patented Quiet Series™ noise/EMI reduction circuitry
- Latchup conforms to JEDEC JED78
- ESD performance:
  - Human body model > 2000V
  - Machine model > 250V

Ordering Code:

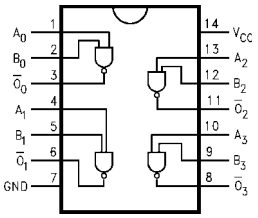
Order Number	Package Number	Package Description
74ALVC00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74ALVC00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Quiet Series™ is a trademark of Fairchild Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +4.6V
DC Input Voltage (V_I)	−0.5V to 4.6V
Output Voltage (V_O) (Note 2)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK})	
V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
DC Output Source/Sink Current	
(I_{OH}/I_{OL})	±50 mA
DC V_{CC} or GND Current per	
Supply Pin (I_{CC} or GND)	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 3)

Power Supply	
Operating	1.65V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	5 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed, limited to 4.6V.

Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		1.65 - 1.95	0.65 x V_{CC}		V
			2.3 - 2.7	1.7		
			2.7 - 3.6	2.0		
V_{IL}	LOW Level Input Voltage		1.65 - 1.95		0.35 x V_{CC}	V
			2.3 - 2.7		0.7	
			2.7 - 3.6		0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 μA	1.65 - 3.6	V_{CC} - 0.2		V
		I_{OH} = −4 mA	1.65	1.2		
		I_{OH} = −6 mA	2.3	2.0		
		I_{OH} = −12 mA	2.3	1.7		
			2.7	2.2		
			3.0	2.4		
		I_{OH} = −24 mA	3.0	2		
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 μA	1.65 - 3.6		0.2	V
		I_{OL} = 4 mA	1.65		0.45	
		I_{OL} = 6 mA	2.3		0.4	
		I_{OL} = 12 mA	2.3		0.7	
			2.7		0.4	
		I_{OL} = 24 mA	3.0			
I_I	Input Leakage Current	0 ≤ V_I ≤ 3.6V	3.6		±5.0	μA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND, I_O = 0	3.6		10	μA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} − 0.6V	3 - 3.6		750	μA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40°C$ to $+85°C$, $R_L = 500\Omega$								Units
		$C_L = 50$ pF				$C_L = 30$ pF				
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Propagation Delay	1.0	3.0		3.5	1.0	3	1.0	4.4	ns

Capacitance

Symbol	Parameter	Conditions	$T_A = +25°C$		Units
			V_{CC}	Typical	
C_{IN}	Input Capacitance	$V_I = 0V$ or V_{CC}	3.3	4.5	pF
C_{PD}	Power Dissipation Capacitance	f = 10 MHz, $C_L = 50$ pF	3.3	23	pF
			2.5	21	
			1.8	20	

AC Loading and Waveforms

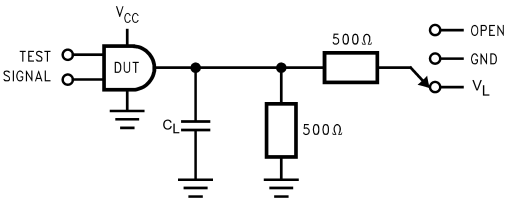


FIGURE 1. AC Test Circuit

TABLE 1. Values for Figure 1

TEST	SWITCH
t_{PLH}, t_{PHL}	Open

TABLE 2. Variable Matrix
(Input Characteristics: f = 1MHz; $t_r = t_f = 2$ns; $Z_0 = 50\Omega$)

Symbol	V_{CC}			
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V	1.8V ± 0.15V
V_{mi}	1.5V	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	1.5V	$V_{CC}/2$	$V_{CC}/2$

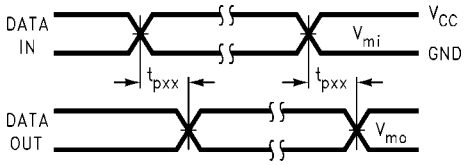
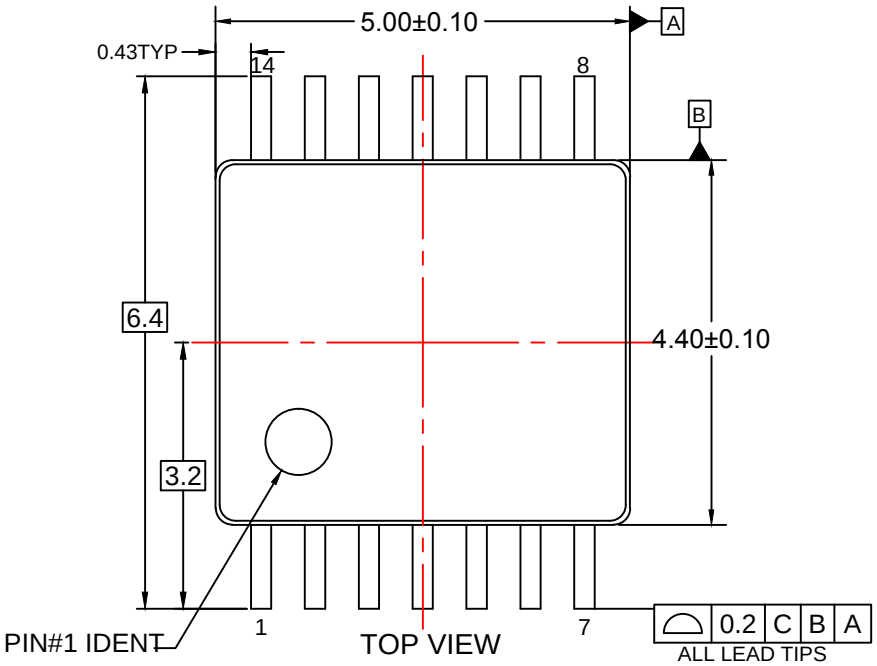
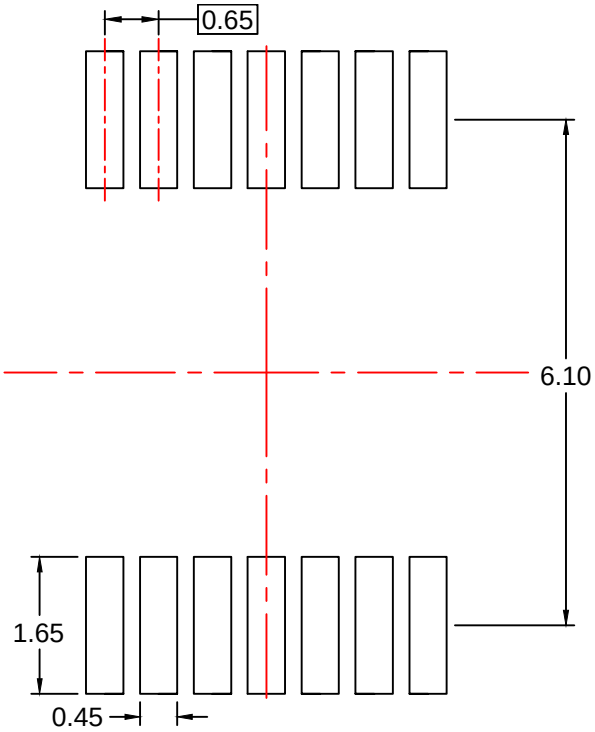


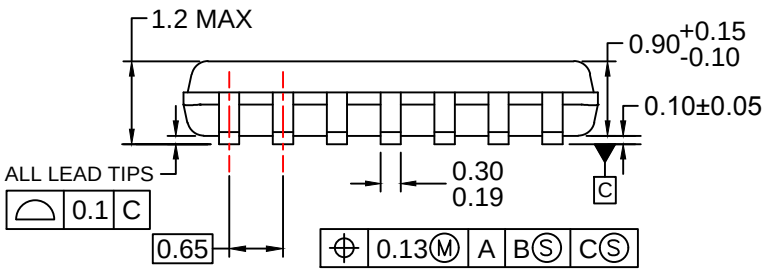
FIGURE 2. Waveform for Inverting and Non-inverting Functions



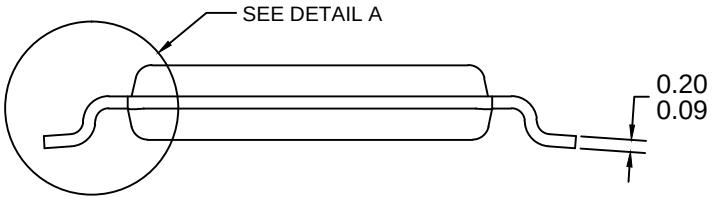
TOP VIEW

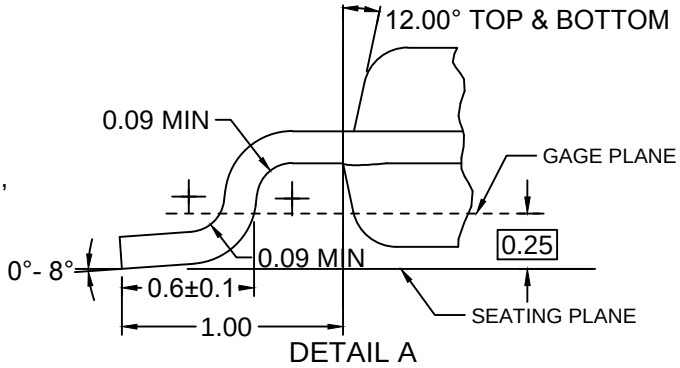


RECOMMENDED LAND PATTERN



FRONT VIEW





DETAIL A

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS

D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 2009.

E. LANDPATTERN STANDARD: SOP65P640X110-14M.

F. DRAWING FILE NAME: MKT-MTC14rev7.

FAIRCHILD.

PUBLICATION ORDERING INFORMATION

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